LOW VOLTAGE (1.24V) ADJUSTABLE PRECISION SHUNT REGULATOR AZ431L

General Description

The AZ431L series ICs are low voltage three-terminal adjustable regulators with guaranteed thermal stability over a full operation range. These ICs feature sharp turn-on characteristics, low temperature coefficient and low output impedance, which make them ideal substitutes for Zener diodes in applications such as switching power supply, charger, motherboard and other adjustable regulators.

The output voltage can be set to any value between 1.24V and 18V with two external resistors.

The AZ431L precision reference is offered in two bandgap tolerance: 0.5% and 1%.

These ICs are available in 4 packages: TO-92, SOT-23-3, SOT-23-5, SOT-89.

Features

- Wide Programmable Precise Output Voltage from 1.24V to 18V
- High Stability under Capacitive Load
- Low Temperature Deviation: 3mV Typical
- Low Equivalent Full-Range Temperature Coefficient: 20PPM/^{o}C Typical
- Low Dynamic Output Resistance: 0.05Ω Typical
- High Sink Current Capacity from 55μA to 100 mA
- Low Output Noise
- Wide Operating Range of -40 to 125^{o}C

Applications

- Graphic Card
- PC Motherboard
- Voltage Adapter
- Switching Power Supply
- Charger

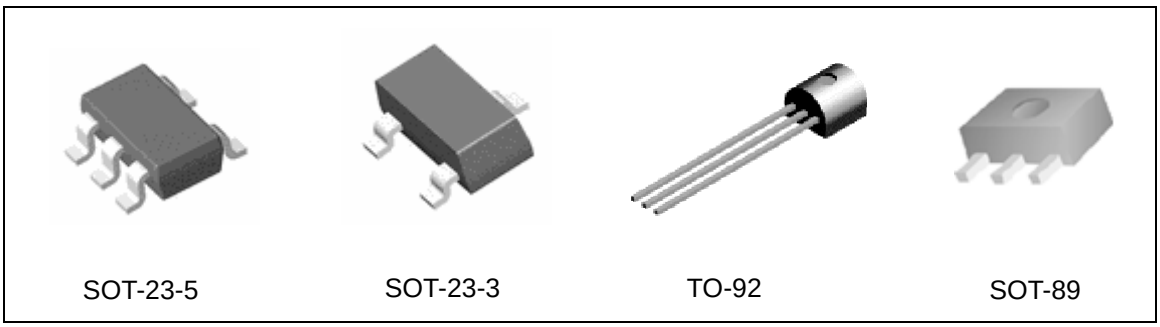


Figure 1. Package Types of AZ431L

Pin Configuration

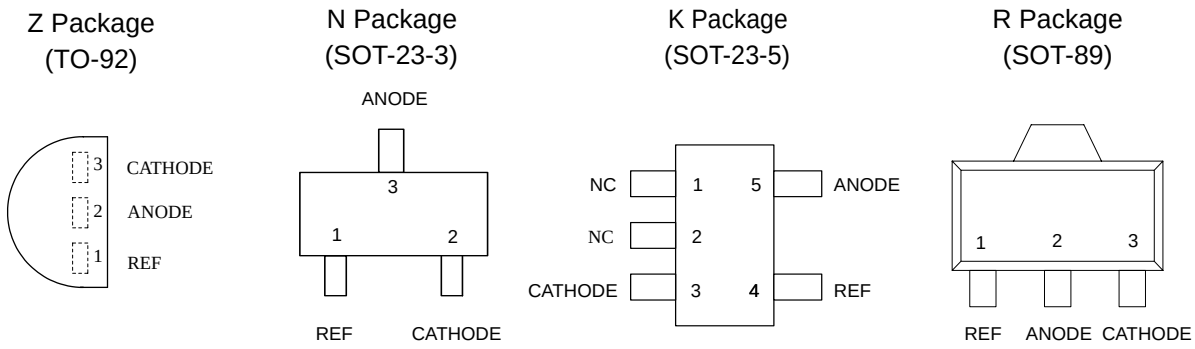


Figure 2. Pin Configuration of AZ431L (Top View)

Functional Block Diagram

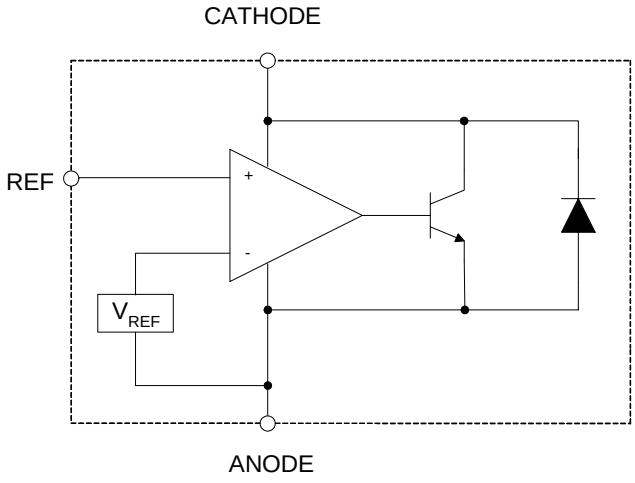
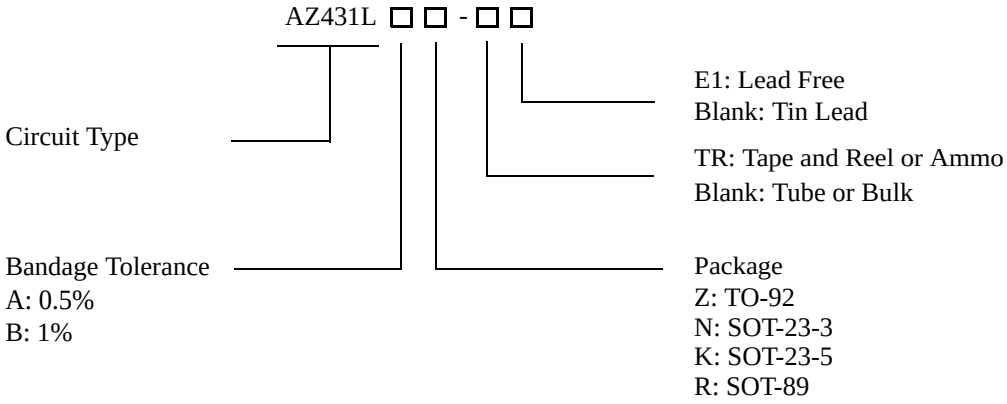


Figure 3. Functional Block Diagram of AZ431L

Ordering Information



Package	Temperature Range	Voltage Tolerance	Part Number		Marking ID		Packing Type
			Tin Lead	Lead Free	Tin Lead	Lead Free	
TO-92	-40 to 125°C	0.50%	AZ431LAZ	AZ431LAZ-E1	AZ431LAZ	AZ431LAZ-E1	Bulk
		0.50%	AZ431LAZTR	AZ431LAZTR-E1	AZ431LAZ	AZ431LAZ-E1	Ammo
		1%	AZ431LBZ	AZ431LBZ-E1	AZ431LBZ	AZ431LBZ-E1	Bulk
		1%	AZ431LBZTR	AZ431LBZTR-E1	AZ431LBZ	AZ431LBZ-E1	Ammo
SOT-23-3	-40 to 125°C	0.50%	AZ431LANTR	AZ431LANTR-E1	N46	EA6	Tape & Reel
		1%	AZ431LBNTR	AZ431LBNTR-E1	N47	EA7	Tape & Reel
SOT-23-5	-40 to 125°C	0.50%	AZ431LAKTR	AZ431LAKTR-E1	K41	E5A	Tape & Reel
		1%	AZ431LBKTR	AZ431LBKTR-E1	K42	E6A	Tape & Reel
SOT-89	-40 to 125°C	0.50%	AZ431LARTR	AZ431LARTR-E1	R41A	E41A	Tape & Reel
		1%	AZ431LBRTR	AZ431LBRTR-E1	R41B	E41B	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Cathode Voltage	V_{KA}	20		V
Cathode Current Range (Continuous)	I_{KA}	-100 to 100		mA
Reference Input Current Range	I_{REF}	10		mA
Power Dissipation	P_D	Z,R Package	770	mW
		N,K Package	370	
Storage Temperature Range	T_{STG}	-65 to 150		°C
Package Thermal Impedance	Q_{JA}	TO-92	130	°C/W
		SOT-23-3	330	
		SOT-23-5	250	
		SOT-89	100	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only , and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Cathode Voltage	V_{KA}	V_{REF}	18	V
Cathode Current	I_{KA}	0.1	100	mA
Operating Ambient Temperature Range		-40	125	°C

Electrical Characteristics

(Typical and limits apply for T_J=25°C unless otherwise noted.)

Parameter		Test Circuit	Symbol	Conditions		Min	Typ	Max	Unit
Reference Voltage	0.5%	4	V_{REF}	$V_{KA}=V_{REF}$, I_{KA}=10mA		1.234	1.240	1.246	V
	1%					1.228	1.240	1.252	
Deviation of Reference Voltage Over-Temperature		4	ΔV_{REF}	$V_{KA}=V_{REF}$ I_{KA}=10mA	0°C to 70°C		2	10	mV
					-40°C to 85°C		3	10	
Ratio of Change in V_{REF} to the Change in Cathode Voltage		5	$\frac{\Delta V_{REF}}{\Delta V_{KA}}$	I_{KA}=10mA, ΔV_{KA}:V_{REF} to 16V			-0.5	-1.5	mV/V
Reference Input Current		5	I_{REF}	I_{KA}=10mA, R1=10KΩ, R2=∞			0.15	0.4	μA
Deviation of Reference Current Over Full Temperature Range		5	ΔI_{REF}	I_{KA}=10mA, R1=10KΩ, R2=∞ T_A=-40 to 85°C			0.1	0.4	μA
Minimum Cathode Current for Regulation		4	I_{KA} (MIN)	$V_{KA}=V_{REF}$			55	80	μA
Off-State Cathode Current		6	I_{KA} (OFF)	V_{REF}=0, V_{KA}=18V			0.04	0.10	μA
				V_{KA}=6, V_{REF}=0			0.01	0.05	
Dynamic Impedance		4	Z_{KA}	$V_{KA}=V_{REF}$, I_{KA}=1 to 100mA f ≤ 1.0kHz			0.05	0.15	Ω

Electrical Characteristics (Continued)

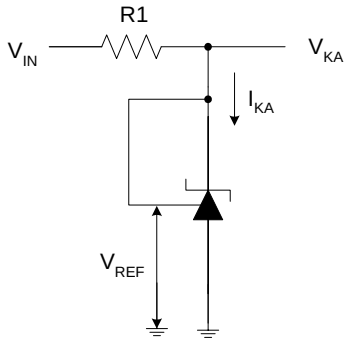


Figure 4. Test Circuit 4 for $V_{KA}=V_{REF}$

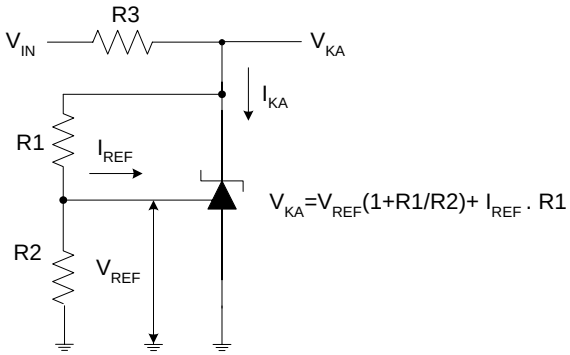


Figure 5. Test Circuit 5 for $V_{KA}>V_{REF}$

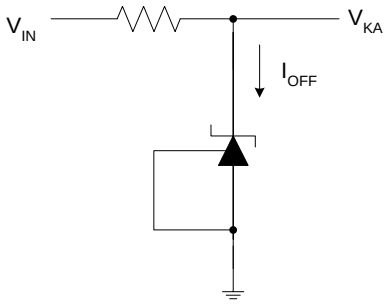


Figure 6. Test Circuit 6 for I_{OFF}

Typical Performance Characteristics

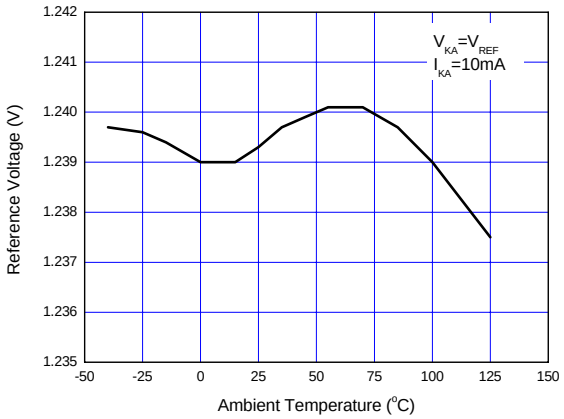


Figure 7. Reference Voltage vs. Ambient Temperature

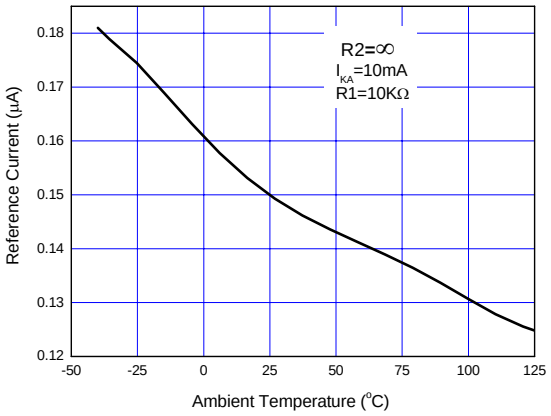


Figure 8. Reference Current vs. Ambient Temperature

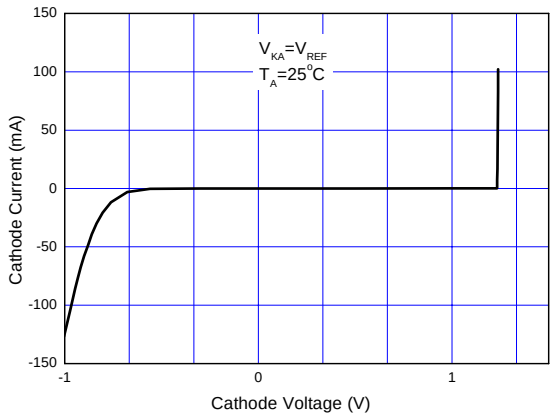


Figure 9. Cathode Current vs. Cathode Voltage

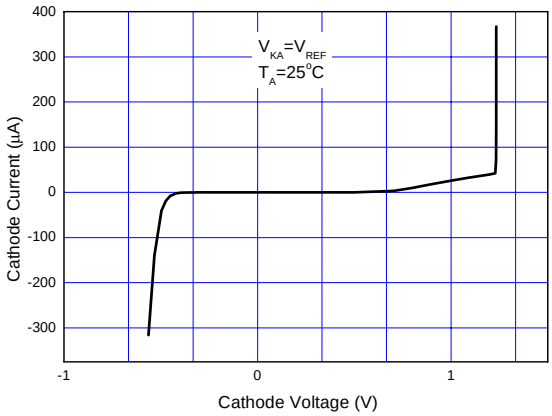


Figure 10. Current vs. Cathode Voltage

Typical Performance Characteristics (Continued)

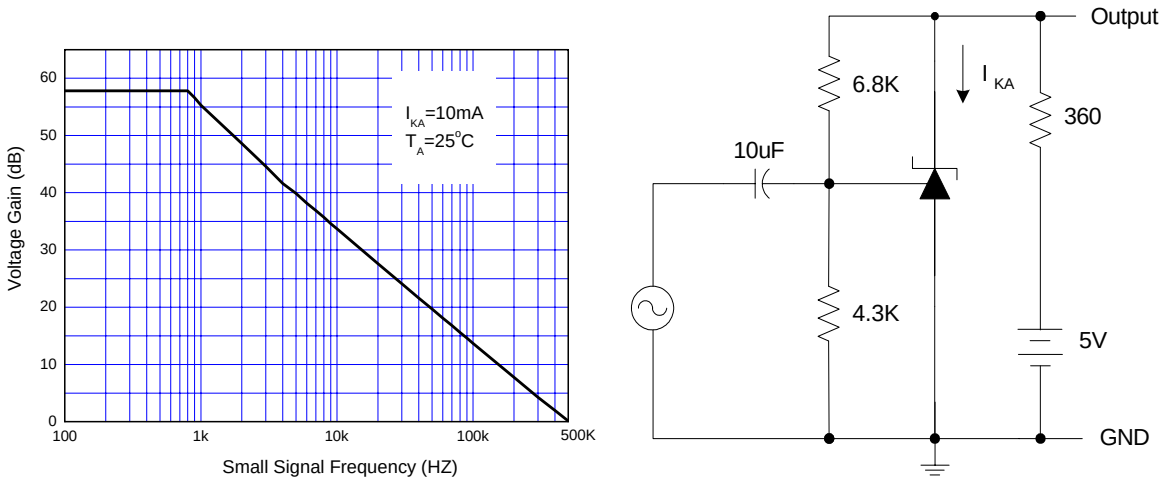


Figure 11. Small Signal Voltage Gain vs. Frequency

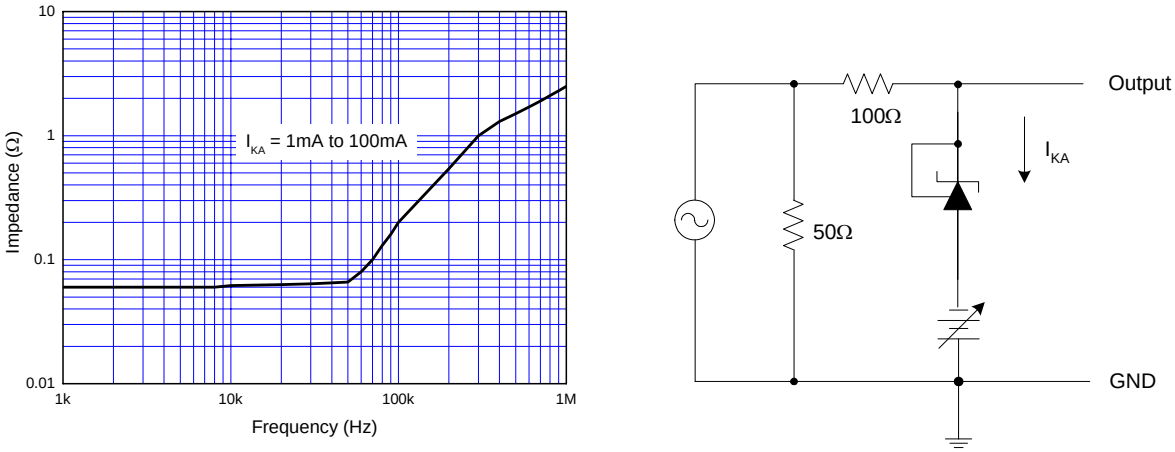


Figure 12. Dynamic Impedance vs. Frequency

Typical Performance Characteristics (Continued)

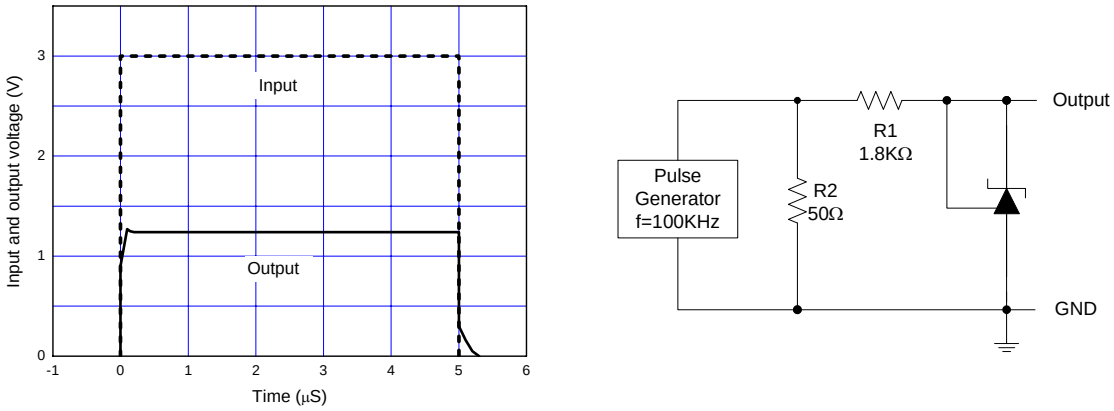


Figure 13. Pulse Response of Input and Output Voltage

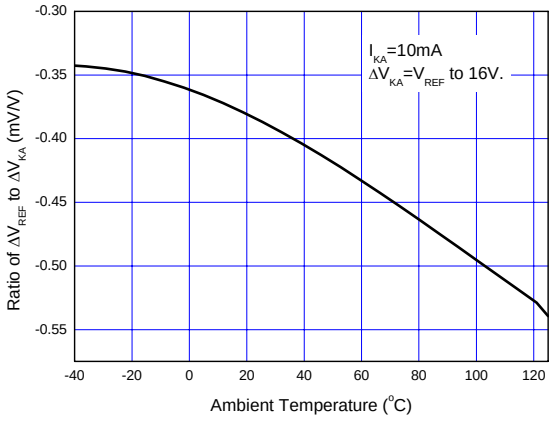


Figure 14. Ratio of Delta Reference Voltage to the Ratio of Cathode Voltage vs. Ambient Temperature

Typical Applications

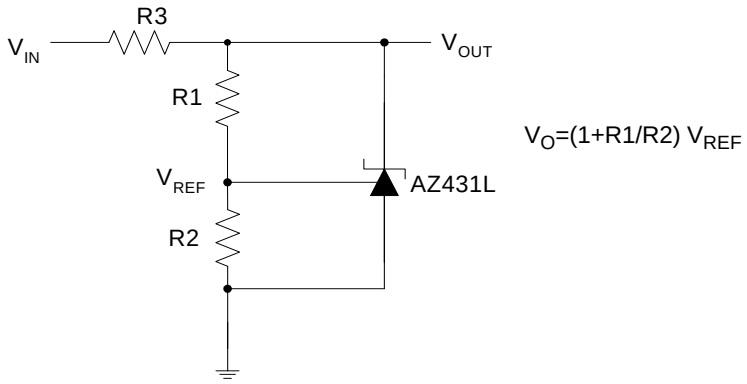


Figure 15. Shunt Regulator

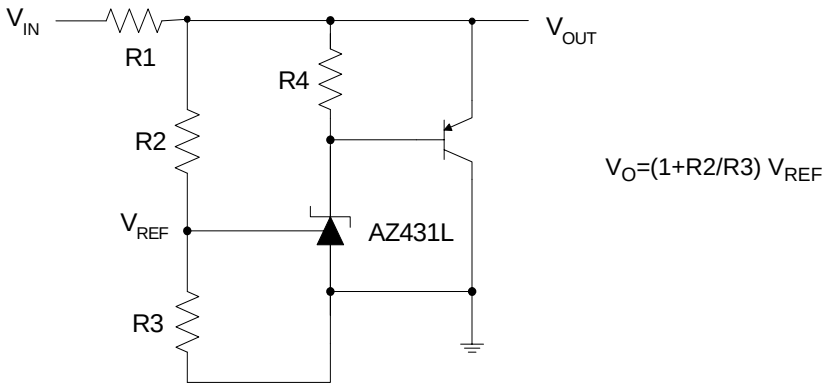


Figure 16. High Current Shunt Regulator

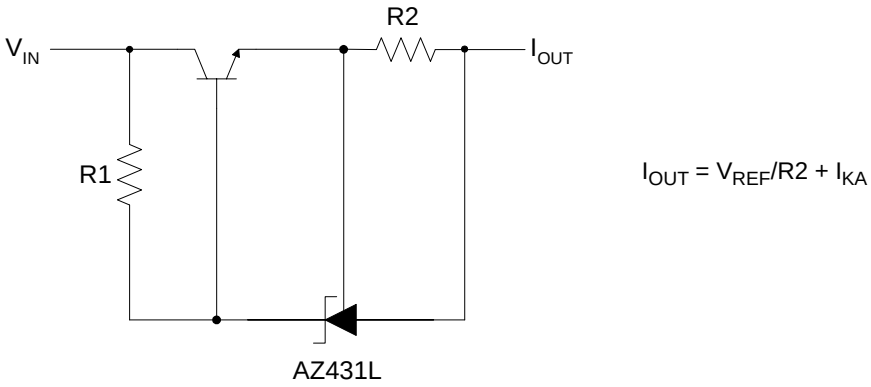


Figure17. Current Source or Current Limit

Typical Application (Continued)

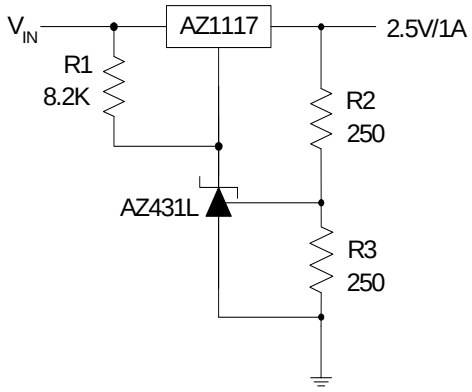


Figure18. Precision 5-V 1.5A Regulator

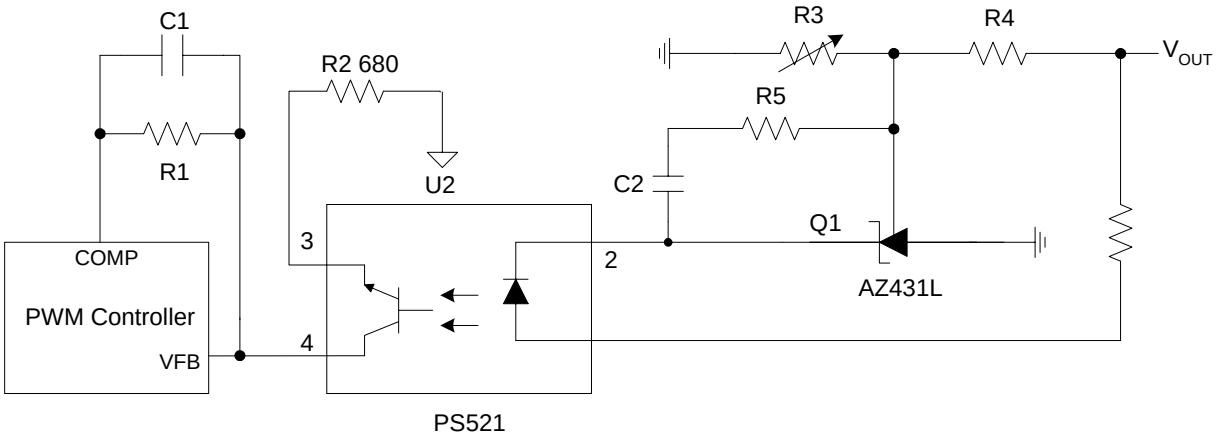
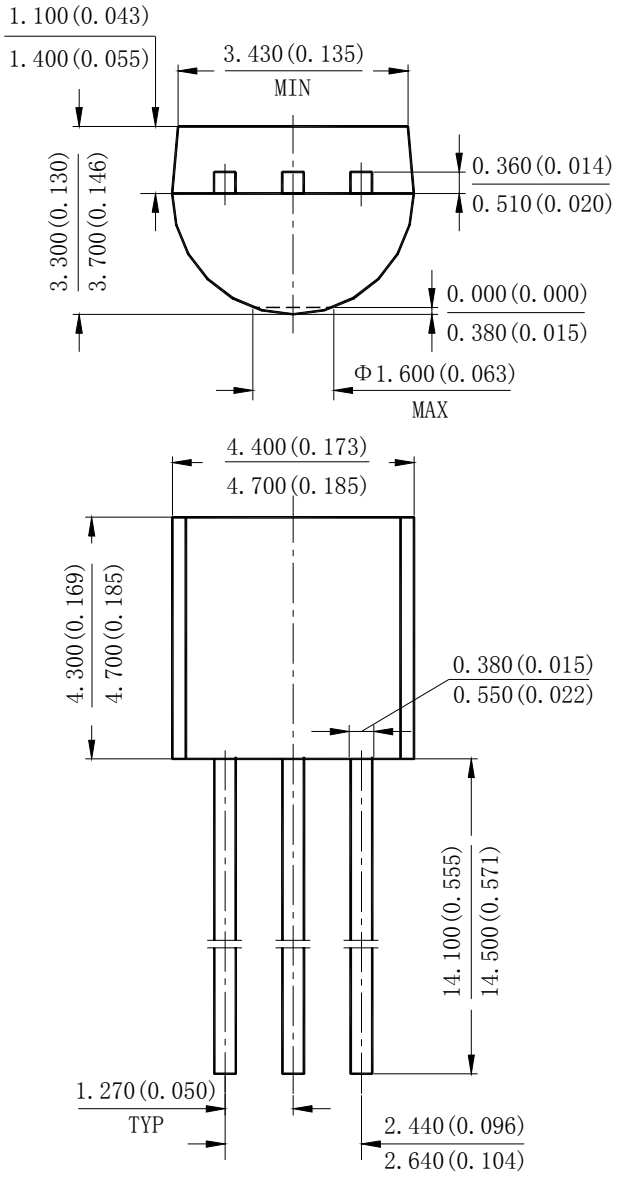


Figure 19. PWM Converter with Reference

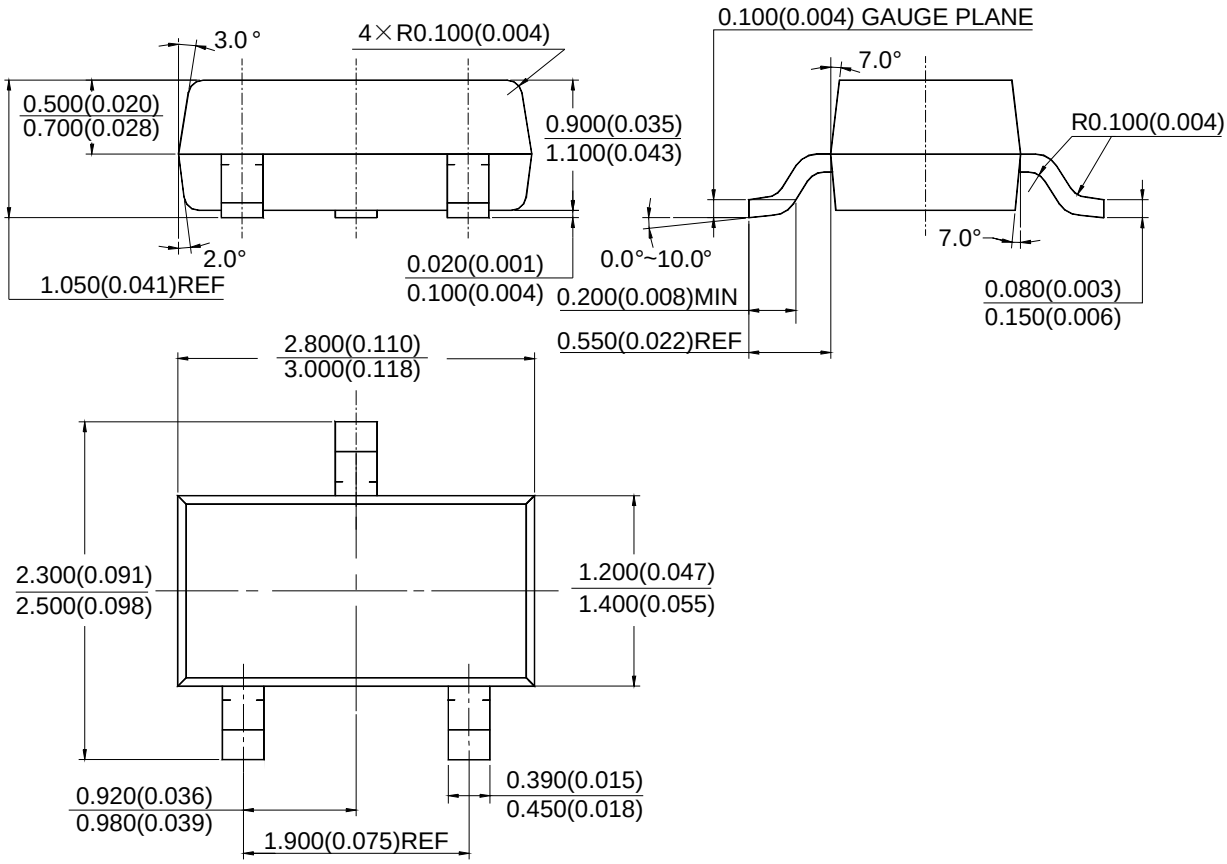
Mechanical Dimensions

TO-92 **Unit: mm (inch)**



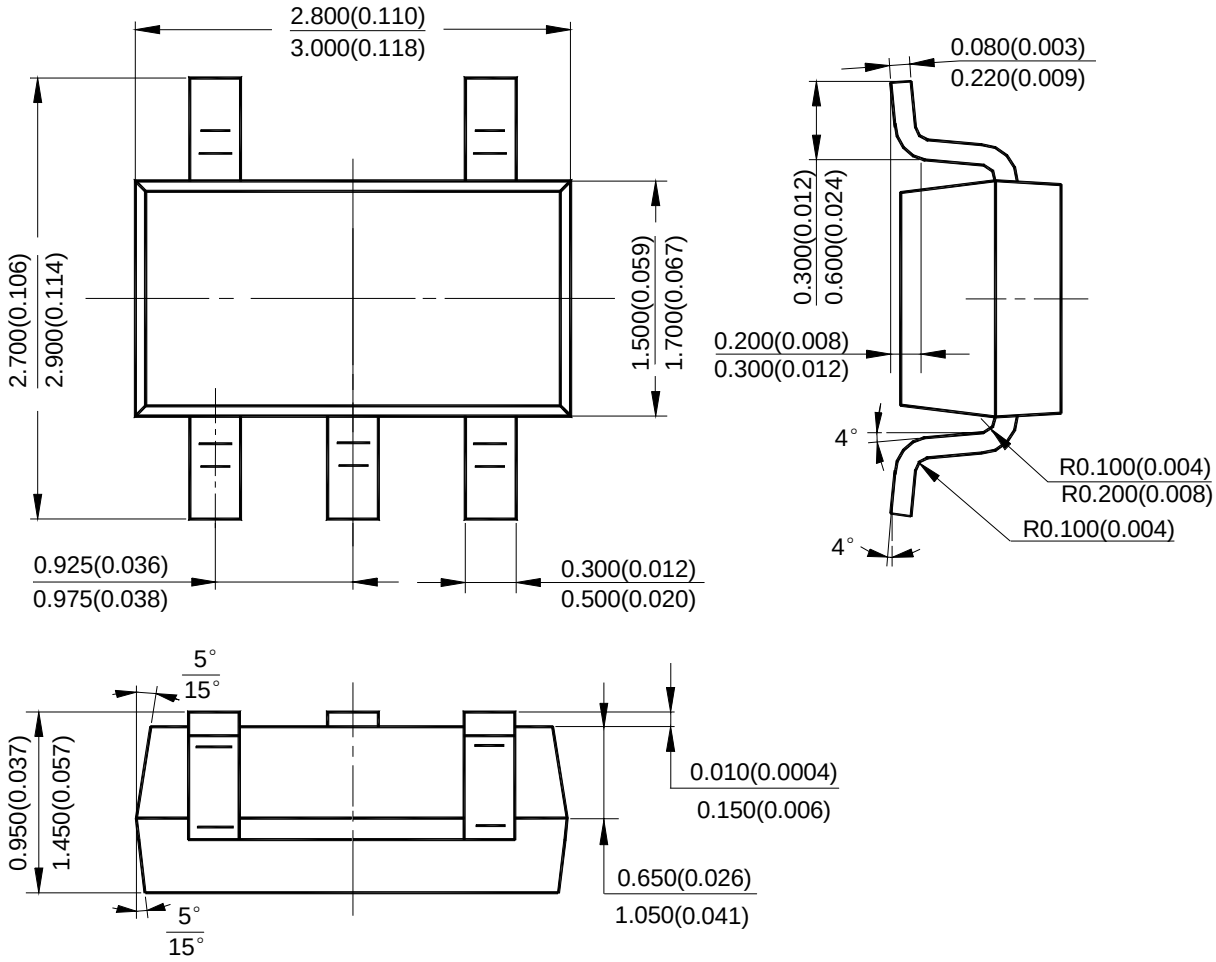
Mechanical Dimensions (Continued)

SOT-23-3 **Unit: mm(inch)**



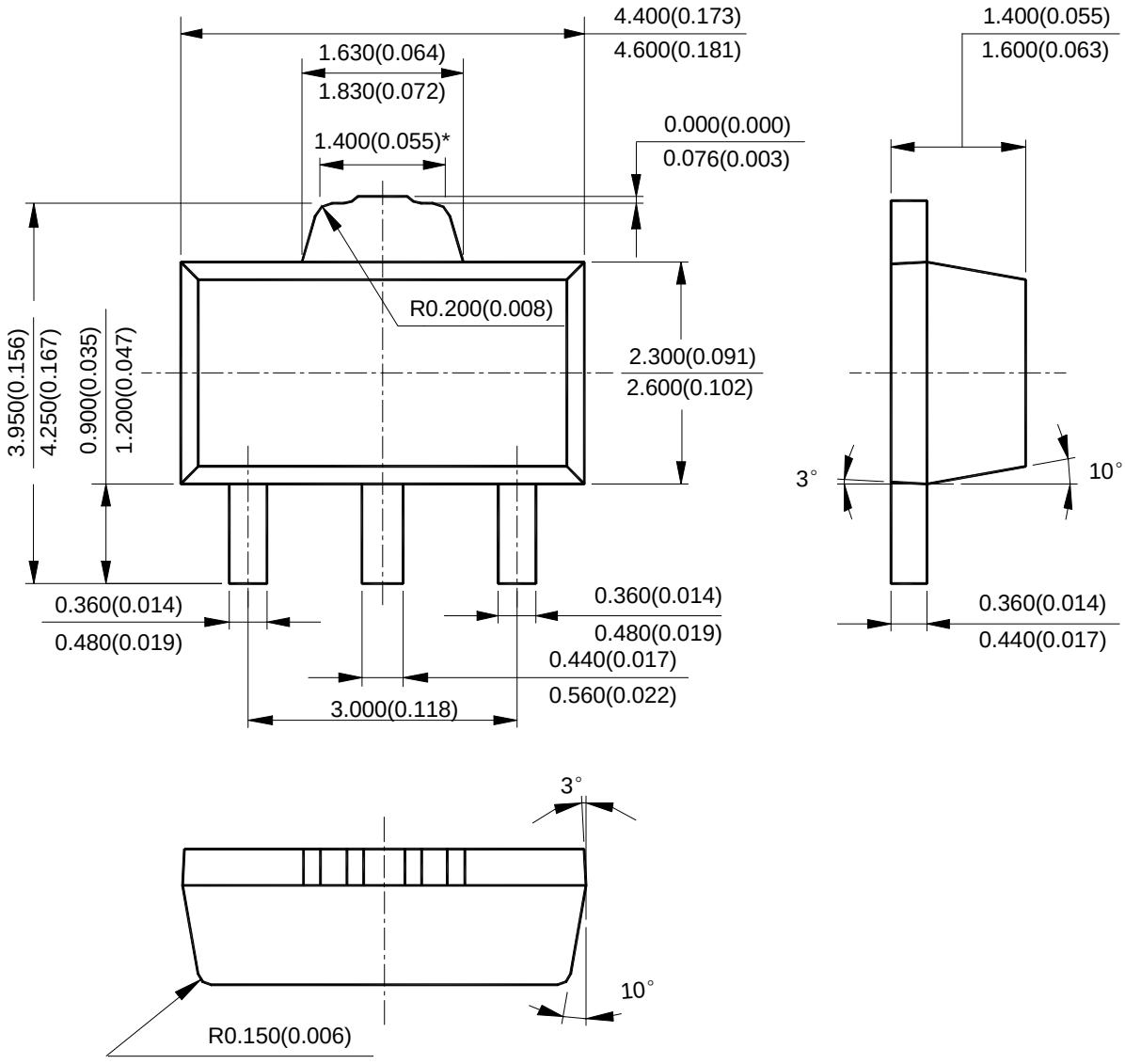
Mechanical Dimensions (Continued)

SOT-23-5 **Unit: mm(inch)**



Mechanical Dimensions (Continued)

SOT-89 **Unit: mm(inch)**



BCD Semiconductor Manufacturing Limited

http://www.bcdsemi.com

BCD Semiconductor Corporation

3170 De La Cruz Blvd, Suite # 105 Santa Clara, CA 95054-2411, U.S.A Tel: +1-408-988 6388, Fax: +1-408-988 6386

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, PRC Tel: +86-21-6485-1491, Fax: +86-21-5450-0008

Advanced Analog Circuits (Shanghai) Corporation

8F, B Zone, 900 Yi Shan Road, Shanghai 200233, PRC Tel: +86-21-6495 9539, Fax: +86-21-6485 9673

BCD Semiconductor (Taiwan) Company Limited

Room 2210, 22nd Fl, 333, Keelung Road, Sec. 1, TaiPei (110), Taiwan Tel: +886-2-2758 6828, Fax: +886-2-2758 6892